

CRMNTL0626A

N-Channel 60V, 28mΩ Typ. Power MOSFET

Description

Features

• 60V, 6A

 $R_{DS(ON)}$ Typ = 28m Ω @ V_{GS} = 10V

 $R_{DS(ON)}$ Typ = 35m Ω @ V_{GS} = 4.5V

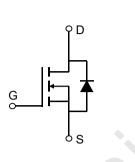
- Advanced Trench Technology
- Excellent R_{DS(ON)} and Low Gate Charge
- Lead Free

Application

PWM Application

• Power Management

· Load Switch



Schematic Diagram

D G S G

Marking and Pin Assignment

Package Marking and Ordering Information

Device	Marking	Package	Outline	Reel Size	Reel (pcs)	Per Carton (pcs)
CRMNTL0626A	0626A	SOT-89-3L	TAPING	7"	1000	32000

D

Absolute Maximum Ratings (@ T_J = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V _{DS}	Drain-to-Source Voltage		60	V
V _{GS}	Gate-to-Source Voltage		±20	V
	Continuous Daois Current	T _A = 25°C	6	А
Ι _D	Continuous Drain Current	T _A = 100°C	3.6	А
I _{DM}	Pulsed Drain Current ⁽¹⁾		24	А
P _D	Power Dissipation	T _A = 25°C	2.23	W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient ⁽²⁾		56	°C/W
T _J , T _{STG}	Junction & Storage Temperature Rang	e	-55 to 150	°C



Electrical Characteristics (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Uni
Off Chara	acteristics					
V _{(BR)DSS}	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	60	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60V, V _{GS} = 0V	-	-	1.0	μA
I _{GSS}	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
On Chara	acteristics				G	
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS} , I_D = 250 μ A	1.1	1.6	2.2	V
R _{DS(ON)}	Static Drain-Source ON-Resistance ⁽³⁾	V_{GS} = 10V, I_{D} = 5A	-	28	36.4	mΩ
		V _{GS} = 4.5V, I _D = 3A	-	35	45.5	mΩ
Dynamic	Characteristics					
C _{iss}	Input Capacitance		-	840	-	pF
C_{oss}	Output Capacitance	V _{GS} = 0V, V _{DS} = 25V, f = 1MHz	Χ-	60	-	pF
C _{rss}	Reverse Transfer Capacitance			50	-	pF
Q _g	Total Gate Charge	0	<u> </u>	20.3	-	nC
Q_{gs}	Gate Source Charge	$V_{GS} = 0$ to 10V $V_{DS} = 30V, I_{D} = 5A$	-	3.7	-	nC
Q_{gd}	Gate Drain("Miller") Charge	$v_{\rm DS} = 30 v, i_{\rm D} = 3A$	-	5.3	-	nC
Switchin	g Characteristics					
t _{d(on)}	Turn-On DelayTime		-	7.6	-	ns
t _r	Turn-On Rise Time	V _{GS} = 10V, V _{DD} = 30V	-	20	-	ns
t _{d(off)}	Turn-Off DelayTime	I_D = 5A, R_{GEN} = 1.8 Ω	-	15	-	ns
t _f	Turn-Off Fall Time		-	24	-	ns
Drain-So	urce Diode Characteristics and M	lax Ratings				
I _S	Maximum Continuous Drain to Source Diode Forward Current			-	6	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	24	А
V_{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _S = 5A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time	1 - 50 di/dt - 1000/	-	13	-	ns
Qrr	Body Diode Reverse Recovery Charge	I _F = 5A, di/dt = 100A/us	_	9	_	nC

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2. $R_{\rm 6JA}$ is measured with the device mounted on a 1inch² pad of 2oz copper FR4 PCB

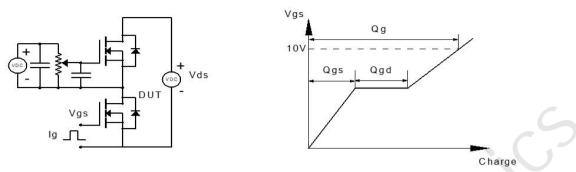
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 0.5%.

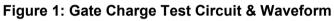


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Test Circuit





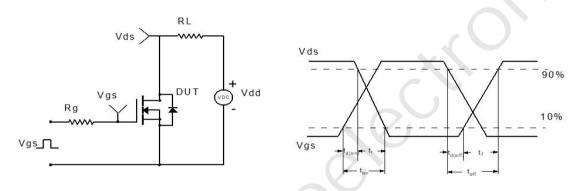
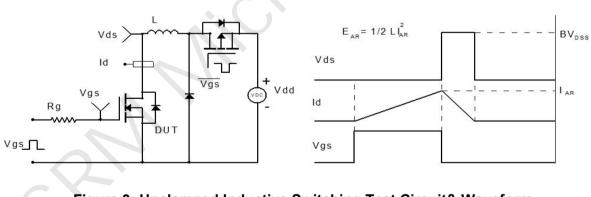
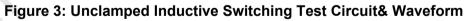


Figure 2: Resistive Switching Test Circuit & Waveform





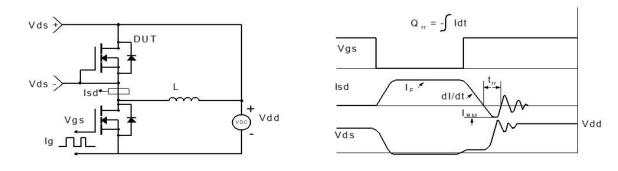
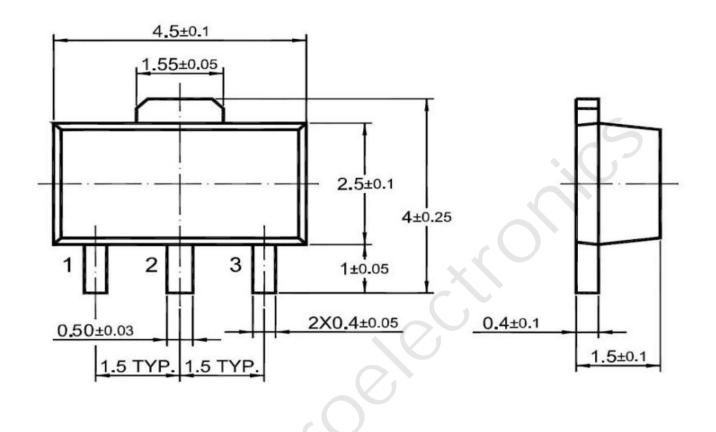


Figure 4: Diode Recovery Test Circuit & Waveform



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Package Mechanical Data(SOT-89-3L)



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